Back-illuminated Si-based photoanode with nickel cobalt oxide catalytic protection layer

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Abstract: Si is an excellent photoabsorber for use in dual band gap photovoltaic cell architecture, but the resulting cell efficiency is hindered by low oxidation potential. We report on the fabrication of a Si self-archiving device, where by introducing a NiCoO2 film on Si, the oxidation potential can be controlled. The device was fabricated with a Si bottom cell, coupled to a tandem device stack. A NiCoO2 film was deposited as a wavelength selective cathodic catalyst for OER, which enhanced the film conductivity of NiCoO2. The device showed high photocurrent (21 mA cm^-2) under red light (38.6 mW cm^-2). Long-term stability tests showed gradual decrease of activity in the beginning, and then the activity was increased, yielding a cathodic shift of the onset voltage (> 50 mV) likely due to a change in the composition of Ni and Co present in KOH. Once the activity of the sample is stabilized, no further degradation was observed for the following 6 days, indicating that the demonstrated back-illuminated photoanode can be considered as a promising architecture to be applied as a bottom cell of the tandem water splitting device under alkaline conditions.

Introduction

For efficient hydrogen (H2) production via water splitting reaction, both hydrogen evolution reaction (HER) and oxygen evolution reaction (OER) need to proceed with a high-rate. However, the kinetically slow OER process has been a major bottleneck, since it comprises several intermediate steps with high activation energy barriers and thus requires a high overpotential (n) to transfer the 4 electrons: \(2H_2O \rightarrow 4H^+ + 4e^-\) (in acidic) or \(4OH^- \rightarrow 2H_2O + O_2 + 4e^-\) (in alkaline). To overcome this problem, efficient OER catalysts are required, but the state of the art electrocatalysts for OER, such as IrO2 and RuO2,[1,2] are precious metal oxides and too expensive to scale-up, despite of their excellent OER activity in acidic media. In this context, earth-abundant transition metal oxides have been extensively investigated to develop cost-effective alternative OER materials with high activity.[3,4] As one of the non-noble catalyst for OER, nickel cobalt oxide (hereinafter NiCoO2) has recently attracted considerable attention, despite the fact that it is stable only in alkaline media, mainly because of its excellent electrical conductivity and rich redox kinetics due to the large number of active sites.[5] Compared to elemental oxides, such as NiO and Co3O4, NiCoO2 is promising candidate for applications, such as electrocatalytic anodic oxygen evolution, supercapacitors, sensors, or optical limiters and switches.[9,10] Similarly in recent studies[11,12] Fe modified NiO compounds have been demonstrated to be efficient OER catalysts. The Boetcher’s group[13] found that Fe enhances the film conductivity of nickel-based oxide, and claimed that incorporated Fe enhances the OER activity through a Ni-Fe partial charge transfer activation process, as has been proposed by Corrigan et al.[15] Furthermore, this study also reported that the overpotential of Ni(OH)2 film for OER can be reduced during cyclic voltammetry (CV) process in 1M KOH due to incorporation of trace amounts of Fe present in KOH.[13] Thus, unintentional, but beneficial Fe alloying or doping occurs. So far, a number of approaches to obtain functional Ni-Fe-O compounds have been reported.[13-16] Large-scale combinational screening studies[17,18] have shown that not only Ni with Fe, but also other metallic elements (e.g., Co, Al, Ce) appear to enhance the OER-activity of Ni based oxides. These recent studies indicate that various combinations of cations provide the possibility to change the electrochemical properties. At the same time, it also implies that the OER activity of NiCoO2 would be also enhanced simply by aging the electrolyte without any intentional doping procedure.

As to date, many research groups have demonstrated catalytic behavior of element nickel or cobalt oxides[16,19-24] while a relatively small number of studies report the electrocatalytic activity of the binary nickel-cobalt oxides.[9,11] In the present work we demonstrate the time-dependant behavior of the OER kinetics of NiCoO2 thin films in 1M KOH (pH = 14) electrolyte. The NiCoO2, with Co interlayer is deposited by DC-sputtering on p’pn’ Si photodetectors, and we evaluate the OER kinetic variation of the sample as a function of the operating time under back side illumination. According to the Pourbaix diagrams, both nickel and cobalt oxide can be converted to hydroxides during potential cycling in alkaline electrolyte.[25,26] and both materials have been used as a protection layer of Si photoabsorbers with frontal illumination.[16,19,22,23] However, in actual tandem device operation conditions a low band gap absorber, such as Si, should be used as bottom cell of the tandem water splitting device, where the light is incident from the “dry”
side of the photoanode. We have demonstrated successful hydrogen production using a light-permeable ring-shaped Al back contact under back-illumination condition,[27] and this approach is also employed in this study to allow illumination from the side opposing the solid/liquid interface (i.e., NiCoO$_x$ side). Since the photons are irradiated from the back contact side, transparency of the protection layer is not a required property, indicating that thick, non-transparent protection layers can be employed.

Results and Discussion

The p-type c-Si with a shallow n'p-junction at the side opposing the solid/liquid interface was coupled with a 50-nm-thick NiCoO$_x$ protective OER catalyst. The NiCoO$_x$ was deposited by co-sputtering of Ni and Co with same deposition rate (i.e., Ni:Co = 1:1) under oxygen flow. The back side of the samples was covered with a quartz glass to protect back side from direct contact with the electrolyte as shown in Figure 1a. The Co interlayer was introduced to prevent oxidation of the Si surface during the metal oxide deposition, and to provide an efficient pathway for the carrier injection by forming an Ohmic contact as shown in energy band diagram (Figure 1b).

First, it was confirmed by energy dispersive X-ray spectroscopy (EDX) analysis (Figure S1 in Supporting Information). The optical behavior of the deposited films was investigated by UV-Vis transmittance spectroscopy as shown in Figure 2. Transmittance of deposited NiCoO$_x$ was only approximately 53% at 600 nm in wavelength in spite of its wide band-gap over 2.75 eV.[28] As shown in our recent work[15] a NiO thin film with 50 nm thickness shows over 80% transmittance at 600 nm wavelength due to its high band gap (3.5 ~ 3.6 eV), and thus the optical loss of Co/NiCoO$_x$ would partially due to the Co interlayer. However, a Co/NiCoO$_x$ layer with same thickness shows transmittance of 43% at the same wavelength having a band-gap of 1.96 ~ 2.36 eV,[29] and it is suggested that the optical loss and decreased band gap of NiCoO$_x$ can be mainly attributed to the mixed cobalt oxide phase which shows a drastic increase of absorption coefficient with increased growth temperature.[30] This illustrates how back illumination is beneficial for photoanodes based on such overlayers.

NiCoO$_x$ is a well-known p-type, mixed-valence oxide with Ni occupying octahedral sites and Co distributed over both octahedral and tetrahedral sites.[31] To confirm the conductivity type of the present NiCoO$_x$ thin film, electrochemical impedance measurements were performed (i.e., Mott–Schottky analysis). The resulting Mott–Schottky plot (Figure S2) shows a negative slope, confirming the p-type behavior of the deposited NiCoO$_x$ films. The flat band potential ($E_{fb}$) and the acceptor density ($N_a$) were estimated to be $E_{fb}$ = 0.7 V versus RHE and $N_a$ = 7·10$^{18}$ cm$^{-3}$, respectively, and this high dopant density should provide sufficient conductivity to transport holes through the valence band.
To verify the photoelectrochemical properties of NiCoO₂, this film was coupled with the n⁺p⁻Si photoanode with a Co interlayer between the p⁻Si and NiCoO₂ regions, and the sample was examined by CV and incident photon to current efficiency (IPCE) measurements. The difference between the overpotentials η required to obtain a 10 mA cm⁻² with the p⁻Si/NiCoO₂ (under dark) and n⁺p⁻Si/NiCoO₂ (38.6 mW cm⁻² under the back illumination) reveals a photovoltage ($V_{ph}$) of ~ 510 mV (Figure S3), which is in good agreement with the $V_{ph}$ determined for our previous p⁺n⁻ Si photocathode with Pt catalyst under same light spectrum condition.²⁷

Figure 3 shows spectrally resolved IPCE measurement results of the n⁺p⁻Si/NiCoO₂ photoanode under back side and front side illumination. Each data point was measured at an applied bias of 1.4 V vs. RHE, at which the sample shows a saturated photocurrent for both front and back side illumination. As shown in Figure 3, the IPCE under the back side illumination increases gradually and shows IPCE close to 85% at 550 nm for photons, which are absorbed near the back side of the sample. Considering the light absorption depth of Si as a function of the wavelength,²⁷ this high IPCE response is natural since the charge collecting pn-junction is placed at the back side of the sample, and this shows that this n⁺p⁻Si/NiCoO₂ structure is an efficient configuration to be used as a bottom cell of the tandem device. The low IPCE response in the short wavelength range (~ 500 nm) is mainly attributed to the high recombination rate at the n⁻Si surface. Note that we did not apply any surface passivation treatment, and there is no significant optical loss due to the quartz cover glass in this wavelength range.²⁷

Conversely, the IPCE of the same sample under front side illumination increases slowly from the short wavelength region and reaches merely 30% at a wavelength of 800 nm because most of the electron-hole pairs are generated far from the pn-junction under the front illumination, and due to the poor transmittance of the NiCoO₂ layer as shown in Figure 2. Note that imperfect active-area definition by epoxy can cause a overrating of IPCE.

In order to investigate time-dependant behavior of the sample, repeated CV measurements with long-term chronoamperometry (CA) measurements were carried out. As shown in Figure 4a, the potential required to achieve a photocurrent density ($J_{ph}$) of 10 mA cm⁻² was found to depend on the operating time. An applied potential of 1.13 V was required for the initial CV curve. This performance compares well our previous study with an as-deposited NiO, which showed relatively gradual slope, requiring an applied potential of ~ 1.24 V to reach the 10 mA cm⁻².

Note that imperfect active-area definition by epoxy (Loctite 1C Hysol) encased electrodes can cause a overrating of IPCE,²³ but not affect on the qualitative behavior. This difference in IPCE behavior between the front and back side illumination is reflected in the CV measurement results (inset in Figure 3). The saturated photocurrent of the n⁺p⁻Si/NiCoO₂ photoanode sample is around 21 mA cm⁻² under the back side illumination with approximate AM 1.5G + 635 nm long pass filters, whereas significantly lower photocurrent, less than 5 mA cm⁻² was measured under front illumination.
This enhanced performance of NiCoO₂ is in good agreement with that from the previous electrochemical study on as-deposited Ni-Co-O OER catalyst. Addition of Co, which abounds in the spinel structure of nickel oxide, is known to provide more active sites, and reduce intrinsic electrical resistivity. Tseung and Jasem suggested that the mixed valences of the nickel and cobalt cations are helpful in the reversible adsorption of oxygen by providing donor-acceptor sites for chemiadsorption, thus lowering the overpotential. Such synergetic effects are not limited to Ni-Co oxides, for instance recent studies on Ni-Fe-O oxides can be understood in the same context. Nevertheless, 1.18 V (at 10 mA cm⁻²) was required for the CV measured after 24 hours chronoamperometry test at 1.2 V, reflecting the changes in OER kinetics. These CV curves (initial and 24h after) showed a similar saturation current Jₛ (~ 22 mA cm⁻²), but they behaved differently. Compared with the initial CV curve, the curve taken after 24 hours had an anodic shift of 20 mV at 10 mA cm⁻² and a decreased slope resulting a significant loss at the maximum power point (lower fill factor), which can result in significant loss of operating current density in tandem devices and can be attributed to the NiCoO₂ catalyst layer. The anodic shift accompanying with the decreased slope might be explained by the reaction of Co-O compounds with the alkaline electrolyte.

Boettcher's group reported in their recent work that ppb-level iron impurities in KOH electrolyte substitute for Co³⁺ under the applied potential, and this substitution incorporation decreases the electrical conductivity of the CoOOH phase, and our IC-P-MS analysis revealed Fe of approximately 30 ppb in the electrolyte. In this report, the reduced conductivity appears as a lowered fill factor (i.e. decreased slope in CV curve). Since our photoanode sample with sputtered CoO₂ showed a continuous anodic shift of onset potential with decreased fill factor, this resulted in an increase in overpotential of approximately 40 mV after 3 days operation (Figure S4). This is in agreement with the recent report by the Lewis’ group that the CoO₂ coupled with a Si photoanode shows a gradual loss in catalytic activity associated with the conversion of CoO₂ to Co(OH)₂ and then to ion-permeable cobalt oxyhydroxide (CoOOH) under the electrical potential applied. Interestingly, the required bias potential to reach 10 mA cm⁻² rebounded in the cathodic direction after the first 24 hours and reached 1.07 V vs. RHE after the 3 days of chronoamperometry measurement. Furthermore, the slope of CV curves increased sharply compared to that of the CV curve taken right after the first 24 hours. Since the photoanode with CoO₂ showed a continuous anodic shift of onset voltage as well as degradation in photocurrent, it appears reasonable to assume that the increased activity is mainly attributed to the incorporation of Fe³⁺ with Ni²⁺. A number of recent studies have revealed that the apparent OER activity of NiO is dramatically affected by small amounts of Fe impurities in alkaline electrolyte, causing a cathodic shift in the OER onset potential. The increased redox peak in Figure 4a also implies a strong interaction of Fe with metal sites, such as Co and/or Ni. The integrated area under the redox feature yields the total charge exchanged between the incorporated ions and the active sites of the electrode, and thus the increased redox features shown in Figure 4a may indicate that a significant number of metallic sites have become electrochemically accessible. The redox wave peak of the oxidative current slightly shifted cathodically for the CV curves taken after 24h and 48h relative to that of the initial CV curve, and then anodically shifted toward the OER current peak.

However, only few studies reported the presence of the negative shift of redox peak. J. M. Marioli et al. observed that this negative shift takes place for the Ni-Cr binary oxide films, whereas single component nickel oxide showed only anodic redox peak shift. S. Kim et al. also reported that the shifts in the Ni³⁺ redox features in the negative direction (> 50 mV) is induced by the presence of Co in the Ni hydrous oxide lattice.
The CA study performed at 1.2 V versus RHE for 3 days (Figure 4b) reflects the above mentioned behavior of CV curves. At a fixed potential of 1.2 V vs. RHE, the \( J_{\text{ph}} \) of the n-type Si/Co/NiCoO dropped quite quickly from around 22 to 20.5 mA cm\(^{-2} \) over about half an hour, after which photocurrent output appears to degrade slowly with constant rate. This degradation continued during the first 20 hours of CA measurement, followed by a slow increase in \( J_{\text{ph}} \) after ~22 hours followed by a stabilized \( J_{\text{ph}} \) from the 3rd day of the CA experiment. Once the \( J_{\text{ph}} \) saturated, the sample showed stable \( J_{\text{ph}} \) output until 144th hours (6 days) without any further changes or degradation (Figure S5).

Assuming that incorporation rate or diffusion rate of Fe thought the ion-permeable oxyhydroxide structures is independent of these, these CV and CA behaviors are interesting. They suggest that Fe incorporation in the beginning is insufficient to lead to increased activity, but sufficient to lead to decreased activity due to the iron incorporated cobalt oxyhydroxide components. Subsequently, the Fe incorporation becomes sufficient to cause an improved OER activity after a certain point. It was found that this V-shape of the Si photoanode with Co/NiCoO is reproducible, as confirmed by an additional CA experiment using a new, but similar, sample showed the same time-dependent behavior (see Figure S6).

The electrochemical properties of NiCoO thin film deposited on electrochemical quartz crystal microbalance (EQCM) sample were investigated by means of CV and CA in 1 M KOH (TraceSelect) under dark condition (Figure 5). The as-deposited NiCoO films (Figure 5, black trace) show quite good performance for the OER. An overpotential of ~380 mV is required to achieve a current density of 10 mA cm\(^{-2} \), which is in good agreement with the overpotentials obtained in the photoelectrochemical tests (Figure 4a). Nevertheless, after 10 cycles the potential at 10 mA cm\(^{-2} \) is shifted anodically by 30 mV. The anodic shift closely resembles the drop in current density in the long-term stability PEC tests and the corresponding anodic shift of the CV curves (Figure 4a). Subsequent 2 hours long CA measurement (Figure 5a inset) showed increase in current density along with mass change during the first 0.5 hours. Afterwards, the NiCoO thin film deposited on EQCM was intentionally doped with Fe (Figure 5b, NiCoO in KOH with 0.5 mM Fe) according to a procedure previously used for NiO thin films.\(^{16} \) The EQCM result (Figure 5b inset) shows a significant increase in mass during treatment of NiO in a Fe-containing solution, which was found to be saturated after ~0.5 h of treatment. This behavior is similar to mass change for as-deposited NiCoO in Figure 5a. We attribute this increase in mass at least partially to Fe incorporation occurring in parallel with oxygen evolution. Interestingly, in the subsequently performed CV measurement (Figure 5b) a cathodic shift of 60 mV compared to the as-prepared NiCoO thin film was observed. Thus, an overpotential of ~320 mV was required to obtain a current density of 10 mA cm\(^{-2} \). This enhanced performance of the Fe-doped NiCoO film is in good agreement with the enhancement during prolonged CA of the NiCoO thin film used for the back-illuminated PEC studies and can therefore be attributed to a self-driven enhancement of nickel cobalt oxide by metallic Fe-contamination during photoelectrochemical oxygen evolution reaction. To further investigate this, X-ray photoelectron spectroscopy (XPS) was performed. XPS measurements were performed on as-prepared NiCoO thin films (prepared on EQCM substrates) and on NiCoO thin films after 24 h of continuous operation at a potential of 1.8 V vs. RHE. Detailed scans of the Ni 2p and Co 2p regions derived from the survey spectra in Figure 6a are included in Figure 6b and 6c. The as-prepared NiCoO thin film consists of a mixture of Ni\(^{2+}/Ni^{3+} \) (at binding energies of 854/856 eV) and Co\(^{2+}/Co^{3+} \) (suggested by the satellite feature at 785 eV). After continuous testing for 24 h XPS measurements reveal that Ni and Co are mainly present in their 3+ oxidation state (binding energy of 856 eV for Ni\(^{3+} \) shown in Figure 6b. For Co\(^{3+} \) a characteristic binding energy of 780.5 eV was measured. Furthermore, the characteristic Co\(^{2+} \) satellite signal at 785 eV was significantly reduced as shown in Figure 6c). The presence of different oxidation states in the as-prepared NiCoO thin film as well as its further oxidation during prolonged testing is in good agreement with previously reported NiO thin films prepared and tested under similar conditions\(^{15} \) and can be ascribed to the transformation into its more porous NiOOH and CoOOH oxidation states which act as hosts for Fe-impurities.\(^{19,36} \) Binding energy increase of O1s peak (Figure S7) for the tested sample is also support the formation of the oxyhydroxide phase.\(^{60} \) The direct detection of Fe by means of XPS was not possible in this case due to the Al source's strong overlap with Ni LMM Auger signal and the unfavorable Fe cross section. Using Mg Kα source, which was not available for the XPS used...
in this work, would allow detection of trace Fe. However, the transformations into more open NiOOH and CoOOH in the NiCoO thin film accompanied with the presented data of NiCoO, studied on EQCM substrate strongly suggest the self-driven enhancement of nickel cobalt oxide by metallic Fe-contamination during prolonged photoelectrochemical oxygen evolution reaction. In addition, Ni and Fe distribution mapped by EDX (Figure S7) of the porous NiCoO deposited on the Si photoanode after 6 days of CA testing at 1.2 V versus RHE also directly supports the presence of Fe, along with above mentioned EQCM results.

Conclusions

A back-illuminated n++p+-Si has been coupled to earth-abundant Ni-Co based catalysts and investigated as photoanode for the oxygen evolution reaction. Specifically we have demonstrated the performance of a n++p+-Si/Co/NiCoO structure, whose pn-junction is formed at the side opposing the solid/liquid interface, may efficiently drive the OER under back side (dry side) illumination which will be the actual operational condition in a tandem water splitting device. Importantly, taking advantage of the synergetic effects between Ni and Co, the NiCoO OER catalyst coating exhibits excellent catalytic activity as well as long-term stability in highly concentrated alkaline media, which makes it a strong candidate for the practical OER catalysts. Interestingly, the photoanode samples activated by NiCoO show a non-trivial time-dependent current-voltage behavior in OER activity. In 1M KOH the sample studied initially exhibits an anodic shift of onset potential, followed by a rebound in the cathodic direction which is likely due to Fe incorporation into Ni-Co oxyhydroxide which acts as a host for Fe incorporation. This work highlights an approach to using a low band gap photoanode in actual tandem device operation condition, and enhancing its photocatalytic activity by simple aging process.

Experimental Section

Sample fabrication

The shallow n+p-junction was produced in p-type (100) czechralski (CZ) Si wafers (Topsil, 1-20 ohm-cm, boron-doped) by a shallow phosphorous ion implantation at 36 keV with a dose of 3x10^{15} cm^{-2}. After annealing a mesa-isolated n+p-Si structure with height of 3 µm is formed at the back side (light illumination side) by photolithography and dry etching (Here, we used Ar, O₂ and CHF₃ gases in an Oxford Instruments RIE80). The front side of the same samples was also doped with boron doping using ion implantation at 100 keV with a dose of 5x10^{16} cm^{-2} to form a thin p+ layer. An Al charge collecting layer with a circular hole for light irradiation was deposited by e-beam evaporation with a metallic shadow mask to make circular rings for light irradiation. More fabrication details also can be found in our previous work[21] and Supporting Information.

Characterization

Photoanodes consisting of n++p+Sic/Co/NiCoO were evaluated under back-side illumination using a 1000 W Xenon lamp (Oriel) with AM 1.5g and 635 nm cut-off filters to appropriately approximate the wavelengths and intensity that this electrode would receive in a practical tandem water splitting device. All CV and chronocamperometry experiments were done in a 3 electrode quartz cell, since intensive corrosion of conventional pyrex can poison or cover the active surface with glass corrosion products,[41] and consequently hinder the light absorption. All (photo) electrochemical measurements were performed in high-purity aqueous 1 M KOH (Aldrich, TraceSELECT®, ≥ 99.999%) using a Bio-Lico VSP potentiostat with EC Lab software. A Pt mesh was used as a counter electrode and the reference was a saturated Hg/HgO electrode (Koslow Scientific Company). The detailed experimental setup and procedure are provided in the Supporting Information. The solution was purged with Ar gas 30 minutes prior to any experiment. Inductively coupled plasma mass spectrometry (ICP–MS) experiments were performed (Thermo Fisher Scientific, iCAP-QC) for the quantification of iron impurity in the electrolyte.

To determine efficiency as a function of wavelength, IPCE measurements were employed. An Oriel 74100 monochromator was combined with the Xenon lamp mentioned above to give monochromatic light. IPCE measurements were carried out from 400 to 800 nm under both front side and back side illumination. To confirm the conductivity type of the present NiCoO thin film, electrochemical impedance measurements were performed (Mott-Schottky plot analysis) under the dark condition. Both IPCE and Mott-Schottky analyses were carried out using same equipment and setup as that used for CV measurements.

The results in the present work also cover the electrochemical stability of the NiCoO film, and therefore, emphasis also has been put on electrochemical measurements using EQCM samples under the dark conditions to monitor the mass change that occurs during the electrochemical reaction. For this purpose, a three electrode setup similar to that of photocatalytic CV and CA measurements was used. The EQCM measurements were performed with a 5 MHz QCM200 supplied by Stanford Research Systems.

In order to determine the structural properties, XPS analysis was carried out in an UHV (ultra-high vacuum) system provided by Thermo Scientific. In this work, an Al Kα X-ray source emitting photons with energy 1486.7 eV has been used.

SEM with EDX was also carried out for the surface morphology and cross-sectional investigations using Quanta FEG SEM. The provided electron beam energy was 5 to 20 kV with a working distance of around 3-4 mm.
This work was performed as a part of the Center for Individual Nanoparticle Functionality (CINF) which is funded by Danish National Research Foundation (DNRF54).

Keywords: oxygen evolution, nickel cobalt oxide, water splitting, solar fuel, photocatalysis

10 cm. The transmittance spectra were recorded using a Varian Cary 1E UV-Vis Spectrophotometer to estimate band-gap and optical absorption of the deposited CoNiCoO$_x$ (NiCoO$_x$ on top) and CoO$_x$ layers on quartz substrate. To avoid the effect of background signal, including the absorption by the substrate and/or light scattering particles in the instrument, a baseline correction using a bare quartz substrate has been carried out prior to the measurements for the NiCoO$_x$ and CoO$_x$ deposited samples.

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Keywords: oxygen evolution, nickel cobalt oxide, water splitting, solar fuel, photocatalysis
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Layout 1:

FULL PAPER

Binary metal oxide under back-illumination: crystalline Si (c-Si) coupled with a thin layer of NiCoO$_x$ is applied as a photoanode for water oxidation under back-side illumination to be used as a bottom cell of the tandem water splitting device. The thin layer of NiCoO$_x$ effectively protects c-Si from the alkaline electrolyte for 6 days under oxygen evolution reaction.

Layout 2:

FULL PAPER

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Title